

TECHNICAL UNIVERSITY OF MOMBASA

FACULTY OF ENGINEERING AND TECHNOLOGY

DEPARTMENT OF MEDICAL ENGINEERING (DME 224)

UNIVERSITY EXAMINATION FOR:

DIPLOMA IN MEDICAL ENGINEERING

EHL 2303: OPTO-ELECTRONICS

END OF SEMESTER EXAMINATION

SERIES: APRIL 2016

TIME: 2HOURS

DATE: Pick Date Select Month Pick Year

Instructions to Candidates

You should have the following for this examination -Answer Booklet, examination pass and student ID This paper consists of **FOUR** questions. Attempt question ONE (Compulsory) and any other TWO questions. **Do not write on the question paper.**

Question ONE (Compulsory)

(a)	(i)	Define quantum yield or quantum efficiency.	(1 mark)
	(ii)	State any TWO photoconductive materials.	(2 marks)
	(iii)	State the THREE main factors that limit the speed of response of	
		photodiodes.	(3 marks)
(b)	(i)	With the aid of a typical variation of current gain ag voltage for an avalanche photodiode, sketch the resp curve.	ainst reverse bias oonse characteristic (3 marks)
	(ii)	Define responsivity.	(1 mark)
(c)	(i)	State TWO applications of LEDs.	(2 marks)

(ii)	Describe the fundamental differences between an LED and a Laser		
	Diode.	(4 marks)	
(iii)	State the THREE methods of Q-Switching.	(3 marks)	
(iv)	Explain Q-Switching.	(5 marks)	

Explain the following terms as used in Luminescent coatings and film devices:

- (i) Cathodo luminescence
- (ii) Photo luminescence
- (iii) Electro luminescence

(6 marks)

Question TWO

(d)

(a)	With the aid of a schematic diagram, outline the main componer communication systems.		nts of a fibre optical (4 marks)
(b)	(i)	With the aid of a characteristic curve diagram, explain response of a silicon photo diode.	n the typical spectral (6 marks)
	(ii)	(ii) Describe the operation of a photodiode using diagrams where the operating point is determined by the loadline. (6 marks)	
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(c) With the aid of circuit symbol and the forward characteristic curve of a light activated switch, explain the operation. (4 marks)

Question THREE

(a)	(i)	Define energy ratio.	(1 mark)	
	(ii)	Describe the photovoltaic cell with its junction opera quadrant of the characteristic curve.	ating in the fourth (6 marks)	
	(iii)	State the inverse law of photoconductive cell.	(1 mark)	
	(iv) Describe the photoconductive cell using the typical resistance-illumination characteristic curve. (6 marks)		resistance-illumination (6 marks)	
(b)	With t	the aid of a diagram, explain how a half-wafer cell is produced. (6 marks)		

Question FOUR

(a)	(i)	State the expression which proposes that the energy of a quarter radiation is directly related to the frequency of radiation.	uantum of (1 mark)
	(ii)	With the aid of a diagram, describe the conditions of the exabsorption and emission by a semiconductor.	nergy (6 marks)
	(iii)	Describe the photofet.	(6 marks)
(b)	With the aid of the circuit symbol and the forward characteristics curve describe t operation of the photo-thyristor as a light activated switch. (7 marks)		rve describe the (7 marks)

Question FIVE

(a)	(i)	Explain the meaning of laser as used in fibre-optic.		
	(ii)	With the aid of energy level diagrams, illustrate absorption, spontaneous, emission and stimulated emission of radiation when excited electron fall to lower energy states.		
			(6 marks)	
	(ii)	Explain the typical laser diode characteristic using the char	acteristic curve. (6 marks)	
(b)	(i)	Define mode dispersion.	(1 mark)	
	(ii)	Explain the following terms:		
		(I) Luminous flux ϕ		
		(II) Luminous intensity I		
			(4 marks)	
	(iii)	State the TWO applications of the Luminescent coating fil	m devices.	
			(2 marks)	